**FEATURES** 

- 175 °C T<sub>J</sub> operation
- · Center tap configuration
- Low forward voltage drop

VS-20CTQ150S-M3, VS-20CTQ150-1-M3

- · High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

## DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	20	A						
V <sub>RRM</sub>		150	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1030	A						
V <sub>F</sub>	10 $A_{pk}$ , $T_J$ = 125 °C (per leg)	0.66	V						
TJ	Range	-55 to +175	°C						

VOLTAGE RATINGS								
PARAMETER	VS-20CTQ150S-M3 VS-20CTQ150-1-M3	UNITS						
Maximum DC reverse voltage	V <sub>R</sub>	150	V					
Maximum working peak reverse voltage	V <sub>RWM</sub>	150 \						

# High Performance Schottky Rectifier, 2 x 10 A

#### 2 3 D<sup>2</sup>PAK (TO-263AB) **TO-262AA** Base Base common common cathode cathode 02 0 2 1 Common 🗄 3 10 Common 0 3

Anode cathode Anode

VS-20CTQ150-1-M3

Anode cathode Anode VS-20CTQ150S-M3

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02

PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub> 2 x 10 A								
V <sub>R</sub>	150 V							
V <sub>F</sub> at I <sub>F</sub>	0.66 V							
I <sub>RM</sub> max.	5.0 mA at 125 °C							
T <sub>J</sub> max.	175 °C							
E <sub>AS</sub>	1.0 mJ							
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA							
Circuit configuration	Common cathode							

SHAY www.vishay.com



COMPLIANT

HALOGEN

FREE

Document Number: 95731



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# Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	L TEST CONDITIONS		VALUES	UNITS			
Maximum average forward per leg			10					
current See fig. 5 per device	I <sub>F(AV)</sub>	50 % duty cycle at $T_C$ = 154 °C, rectangular waveform		20	А			
Maximum peak one cycle	I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated	1030	A			
non-repetitive surge current per leg See fig. 7		10 ms sine or 6 ms rect. pulse	load condition and with rated V <sub>RRM</sub> applied	180				
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 2 mH		1.0	mJ			
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1	А			

ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TYP.	MAX.	UNITS				
		10 A	T.I = 25 °C	0.80	0.88	v			
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	20 A	1j=25 C	0.90	1.0				
See fig. 1		10 A	T.I = 125 °C	0.63	0.66				
		20 A	1J = 125 C	0.73	0.77				
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	3.0	25	μA			
See fig. 2		T <sub>J</sub> = 125 °C	$v_{\rm R} = haleu v_{\rm R}$	2.7	5.0	mA			
Typical junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		-	280	pF			
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body			8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	-	10 000	V/µs				

## Note

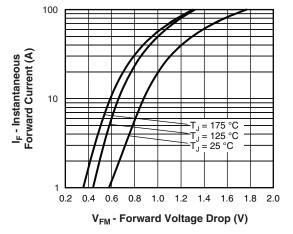
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

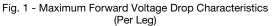
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	PARAMETER		TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			
Maximum thermal resistance,	per leg	D	DC operation	2.0	°C/W			
junction to case	per package	R <sub>thJC</sub>	DC operation	1.0				
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased (Only for TO-262)	0.50	0,11			
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
Marking device		Case style D <sup>2</sup> PAK (TO-263AB)		20CTQ150S				
			Case style TO-262AA	20CTQ	150-1			

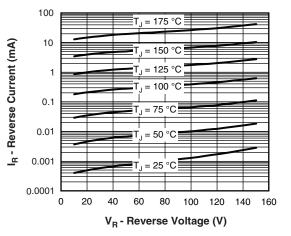


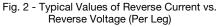
# VS-20CTQ150S-M3, VS-20CTQ150-1-M3

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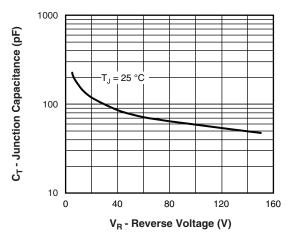
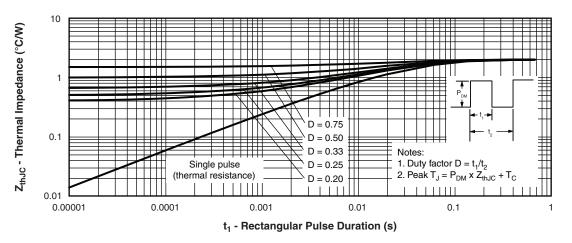
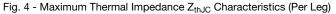


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)





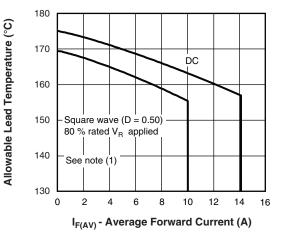
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# VS-20CTQ150S-M3, VS-20CTQ150-1-M3





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Fig. 5 - Maximum Average Forward Current vs. Allowable Lead Temperature

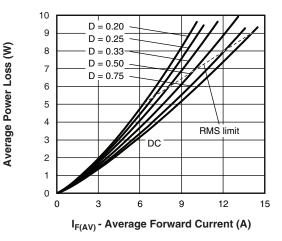


Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

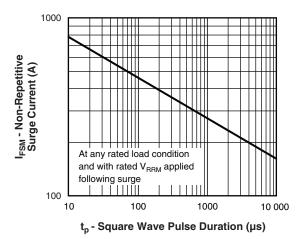


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

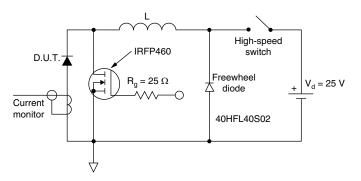


Fig. 8 - Unclamped Inductive Test Circuit

## Note

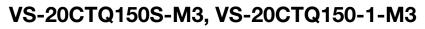
<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \ - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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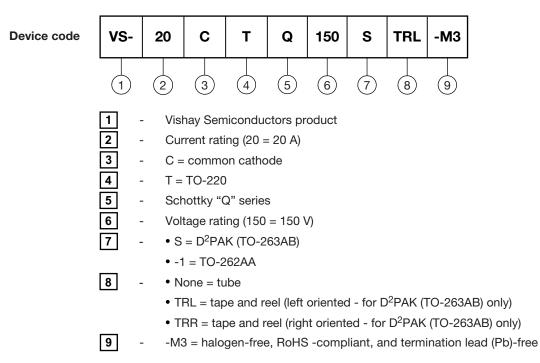


# **Vishay Semiconductors**

## **ORDERING INFORMATION TABLE**

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ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-20CTQ150S-M3	50	Antistatic plastic tubes						
VS-20CTQ150STRL-M3	800	13" diameter plastic tape and reel						
VS-20CTQ150STRR-M3	800	13" diameter plastic tape and reel						
VS-20CTQ150-1-M3	50	Antistatic plastic tubes						

LINKS TO RELATED DOCUMENTS								
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164						
	TO-262AA	www.vishay.com/doc?96165						
Part marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444						
	TO-262AA	www.vishay.com/doc?95443						
Packaging information		www.vishay.com/doc?96424						

# **Outline Dimensions**



D<sup>2</sup>PAK

## **DIMENSIONS** in millimeters and inches

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SYMBOL	MILLIMETERS		INC	INCHES		NOTES SYMB	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

Revision: 08-Jul-15

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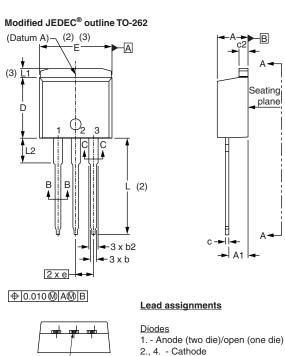
# **Outline Dimensions**



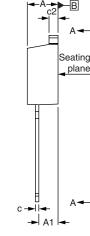
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**TO-262** 

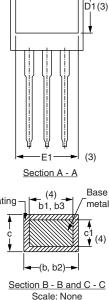
## **DIMENSIONS** in millimeters and inches



Lead tip -



E1 Plating



Е

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. А 4.06 4.83 0.160 0.190 2.03 A1 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 b1 0.51 0.89 0.020 0.035 4 b2 1.14 1.78 0.045 0.070 1.14 1.73 0.045 0.068 4 b3 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 1.65 0.045 0.065 c2 D 8.51 9.65 0.335 0.380 2 D1 6.86 8.00 0.270 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 0.100 BSC 2.54 BSC е L 13.46 14.10 0.530 0.555 L1 \_ 1.65 0.065 3 \_ 3.36 0.132 0.146 L2 3.71

3. - Anode

## Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC TO-262 except A1 (maximum), (6) b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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Document Number: 95419

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